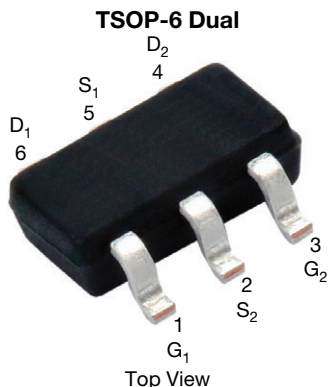


# Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET



Marking code: 8X

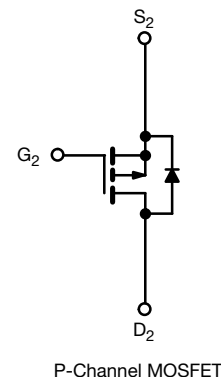
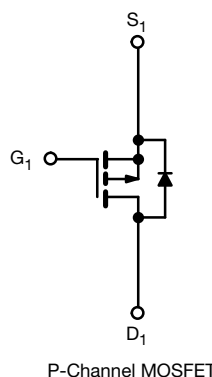
PRODUCT SUMMARY	
$V_{DS}$ (V)	-30
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = -10$ V	-0.110
$R_{DS(on)}$ ( $\Omega$ ) at $V_{GS} = -4.5$ V	-0.185
$I_D$ (A)	-2.75
Configuration	Dual
Package	TSOP-6

## FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 %  $R_g$  and UIS tested
- Material categorization:  
for definitions of compliance please see  
[www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		$V_{DS}$	-30	V
Gate-source voltage		$V_{GS}$	$\pm 20$	
Continuous drain current ( $T_J = 150$ °C) <sup>a</sup>	$T_C = 25$ °C	$I_D$	-3	A
	$T_C = 125$ °C		-1.74	
Pulsed drain current		$I_{DM}$	-11	
Continuous source current (diode conduction) <sup>a</sup>		$I_S$	-2.1	W
Maximum power dissipation <sup>a</sup>	$T_C = 25$ °C	$P_D$	1.67	
	$T_C = 125$ °C		0.56	
Unclamped inductive surge UIS		$I_{AV}$	-5	A
Operating junction and storage temperature range		$T_J, T_{stg}$	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Maximum junction-to-ambient <sup>a</sup>	Steady state	$R_{thJA}$	150	°C/W
Maximum junction-to-foot (drain)	Steady state	$R_{thJF}$	90	

## Note

a. Surface mounted on 1" x 1" FR4 board

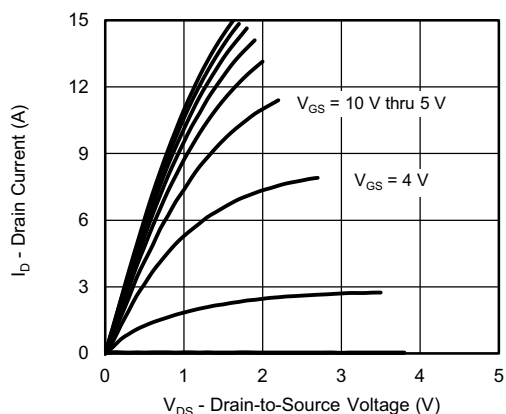
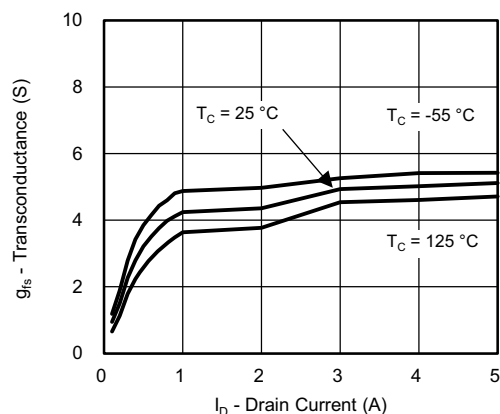
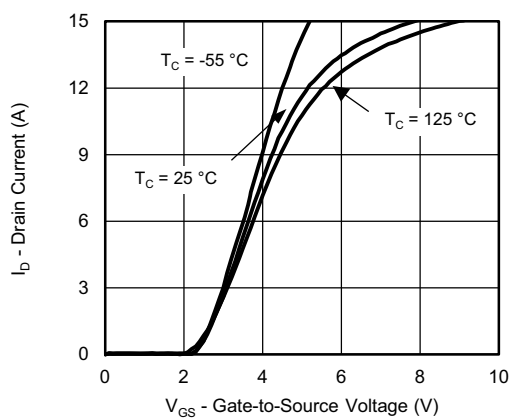
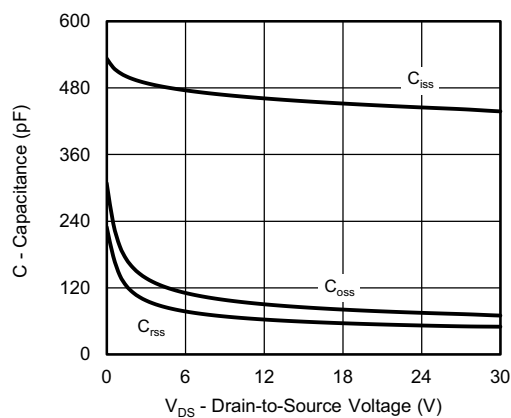
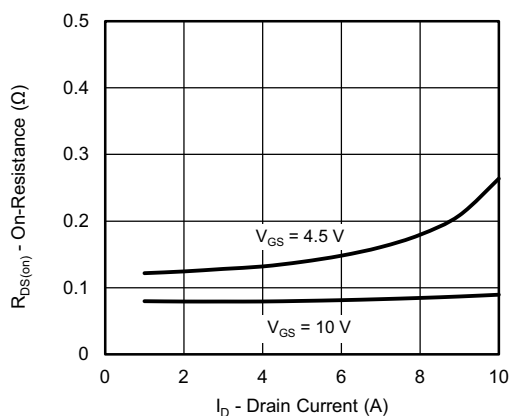
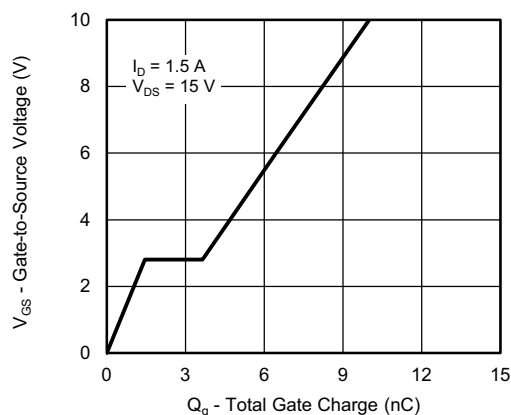


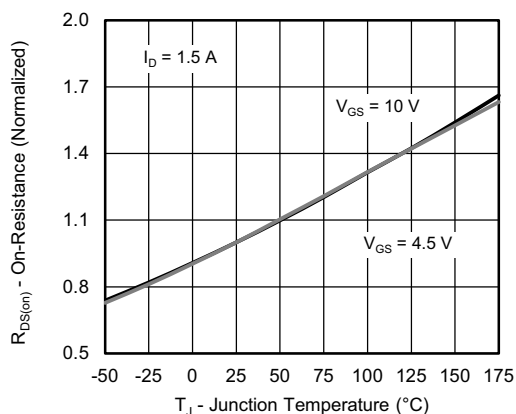
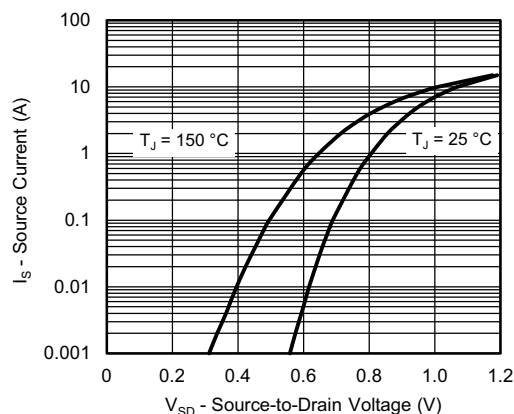
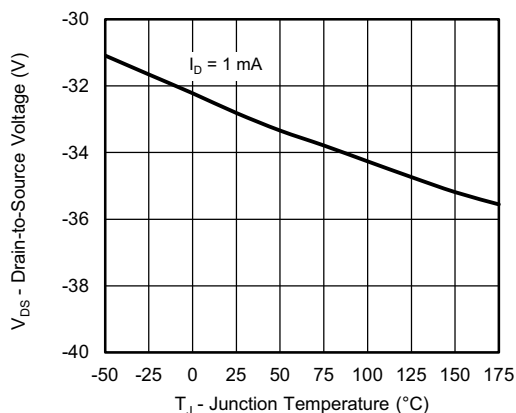
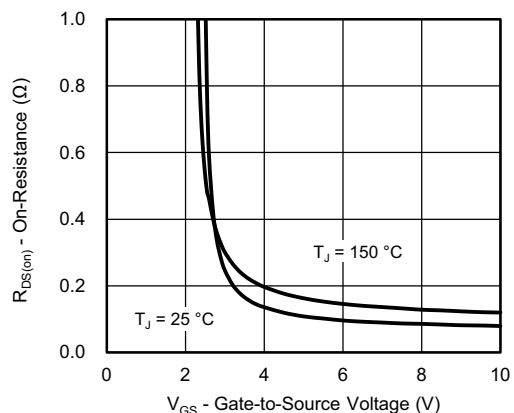
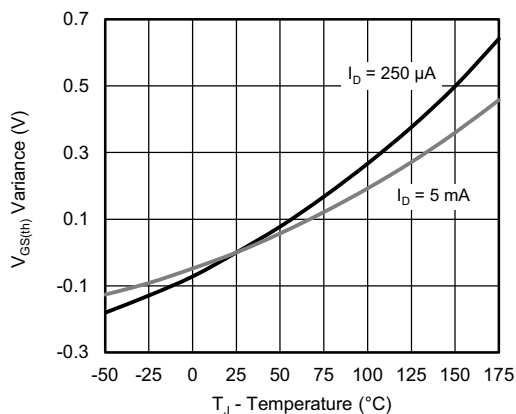
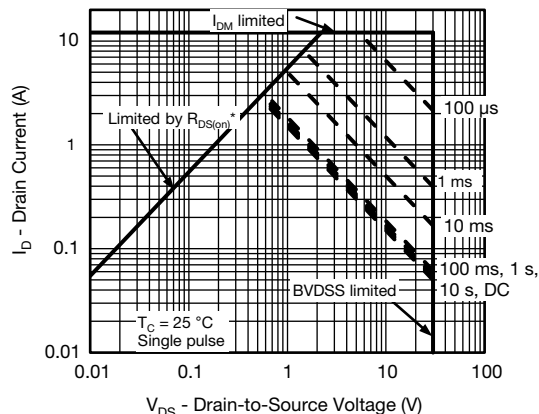
SPECIFICATIONS (T <sub>J</sub> = 25°C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Gate threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250 μA		-1.5	-	-2.5	V
Gate-body leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ± 20 V		-	-	± 100	nA
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -30 V	-	-	-1	μA
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -30 V, T <sub>J</sub> = 175 °C	-	-	-50	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V	V <sub>DS</sub> ≤ -5 V	-4	-	-	A
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -1.5 A	-	0.085	0.133	Ω
		V <sub>GS</sub> = -4.5 V	I <sub>D</sub> = -2 A	-	0.135	0.185	
Forward transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = -5 V, I <sub>D</sub> = -1 A		-	4.2	-	S
Diode forward voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = -0.5 A, V <sub>GS</sub> = 0 V		-	-0.83	-1.10	V
Dynamic <sup>b</sup>							
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -15 V	-	456	570	pF
Output capacitance	C <sub>oss</sub>			-	85	106	
Reverse capacitance	C <sub>rss</sub>			-	59	74	
Total gate charge	Q <sub>g</sub>	V <sub>GS</sub> = -10 V	V <sub>DS</sub> = -15 V, I <sub>D</sub> = -3 A	-	9.7	12.2	nC
Gate-source charge	Q <sub>gs</sub>			-	1.3	-	
Gate-drain charge	Q <sub>gd</sub>			-	2	-	
Gate resistance	R <sub>g</sub>	f = 1 MHz		9	-	24	Ω
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DD</sub> = -10 V, R <sub>L</sub> = 10 Ω, I <sub>D</sub> ≅ -1 A, V <sub>GEN</sub> = -10 V, R <sub>g</sub> = 1 Ω		-	6.6	8.3	ns
Rise time	t <sub>r</sub>			-	2.4	3	
Turn-off delay time	t <sub>d(off)</sub>			-	18.4	23	
Fall time	t <sub>f</sub>			-	2.2	2.8	
Source-Drain Diode Ratings and Characteristic <sup>b</sup>							
Pulsed current	I <sub>SM</sub>			-	-	-11	A
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> = 0.5 A, V <sub>GS</sub> = 0 V		-	-0.83	-1.1	V
Reverse recovery fall time	t <sub>a</sub>	V <sub>DD</sub> = -24 V, I <sub>FM</sub> = -1.5 A, di/dt = 100 A/μs, R = 160 Ω, L = 1 mH, pulse W = 2 μs		-	9.1	-	ns
Reverse recovery rise time	t <sub>b</sub>			-	4.8	-	ns
Body diode reverse recovery time	t <sub>rr</sub>			-	14	28	ns
Body diode reverse recovery charge	Q <sub>rr</sub>			-	9	18	μC
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	-1.4	-	A

**Notes**

- a. Pulse test; pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\ \%$   
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS** (25 °C unless otherwise noted)

**Output Characteristics**

**Transconductance**

**Transfer Characteristics**

**Capacitance**

**On-Resistance vs. Drain Current**

**Gate Charge**

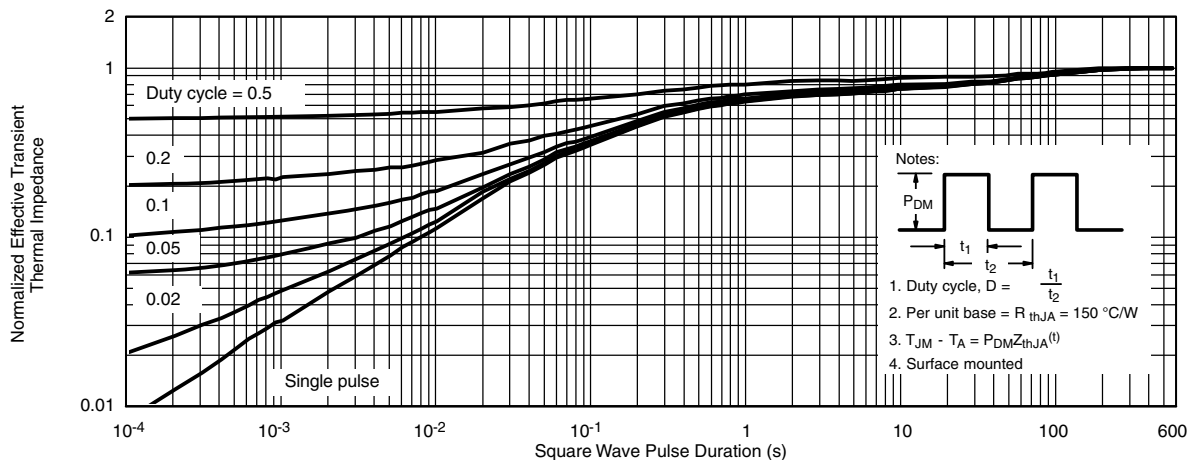
**TYPICAL CHARACTERISTICS** (25 °C unless otherwise noted)

**On-Resistance vs. Junction Temperature**

**Source-Drain Diode Forward Voltage**

**Drain Source Breakdown vs. Junction Temperature**

**On-Resistance vs. Gate-to-Source Voltage**

**Threshold Voltage**


\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

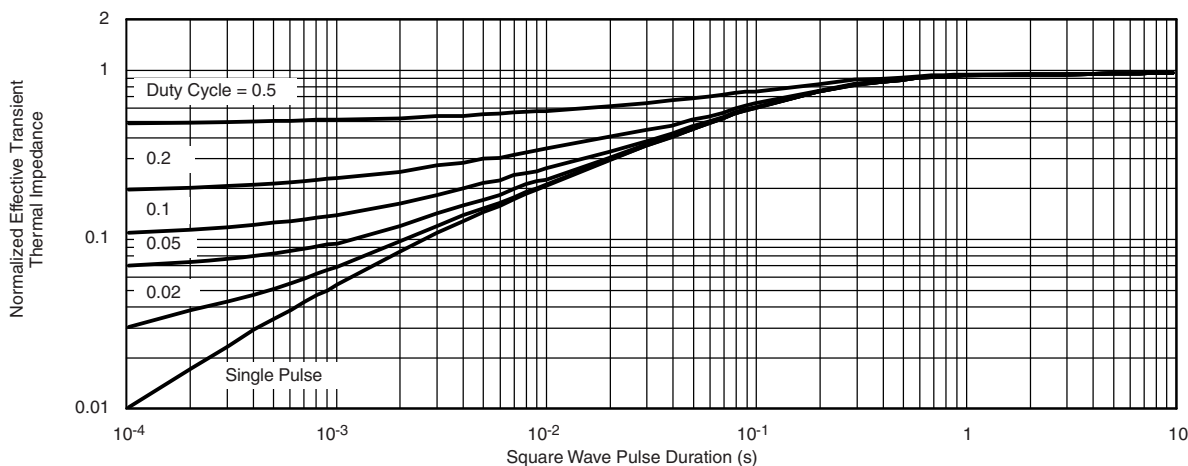
**Safe Operating Area, Junction-to-Case**



**TYPICAL CHARACTERISTICS** (25 °C unless otherwise noted)



**Normalized Thermal Transient Impedance, Junction-to-Ambient**



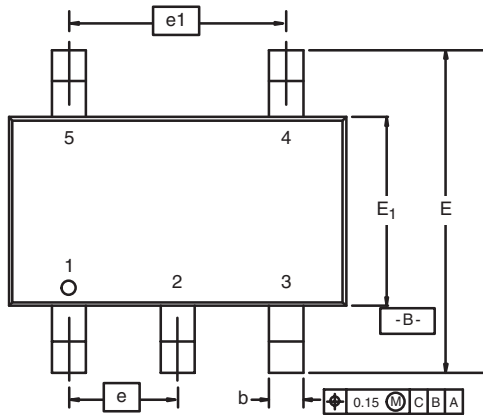
**Normalized Thermal Transient Impedance, Junction-to-Foot**

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?75315](http://www.vishay.com/ppg?75315).

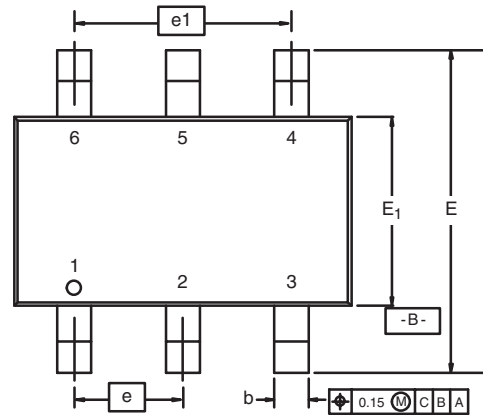


## TSOP: 5/6-LEAD

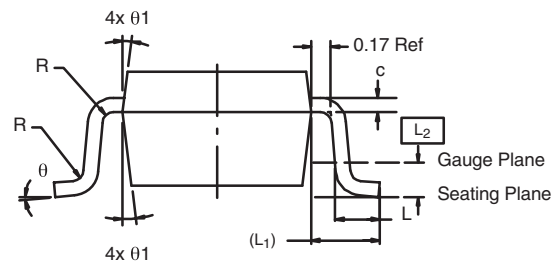
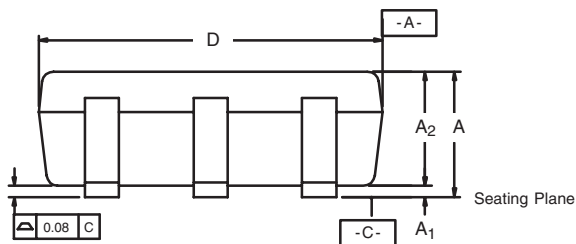
JEDEC Part Number: MO-193C



5-LEAD TSOP

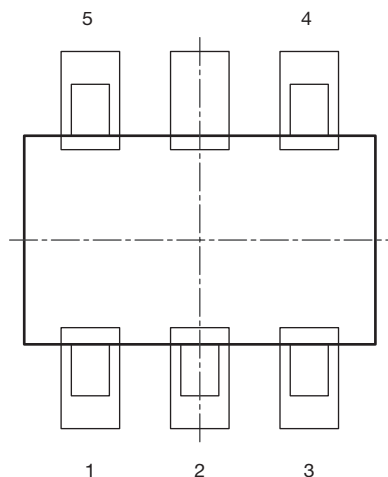


6-LEAD TSOP

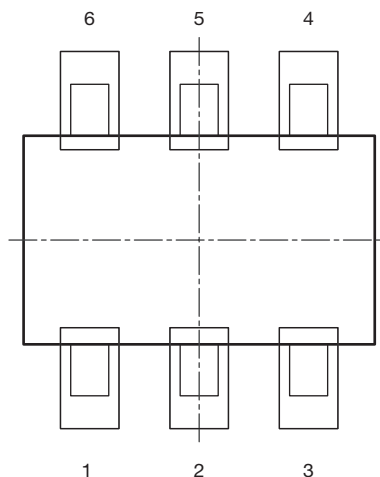


	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004
A <sub>2</sub>	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e <sub>1</sub>	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L <sub>1</sub>	0.60 Ref			0.024 Ref		
L <sub>2</sub>	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ <sub>1</sub>	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06						
DWG: 5540						

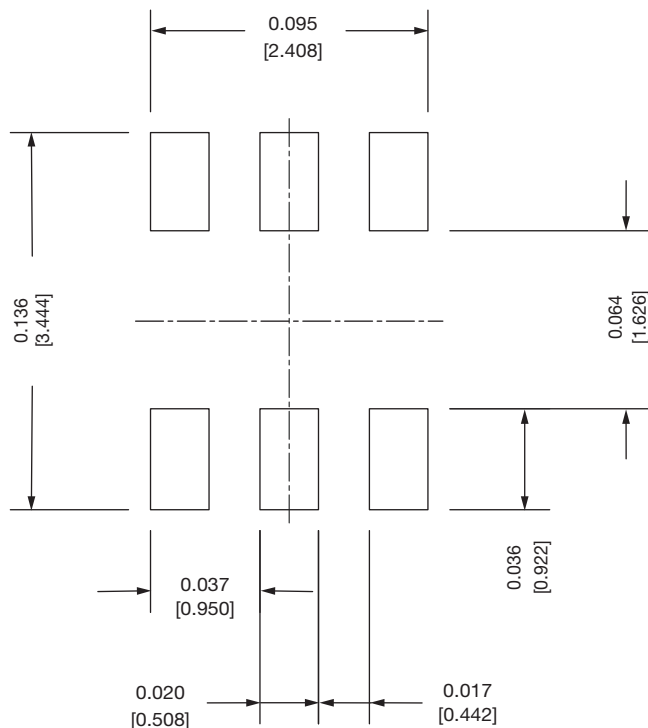
## Recommended Land Pattern For TSOP-5L / TSOP-6L



TSOP 5L



TSOP 6L


**Note**

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022  
DWG: 3010



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